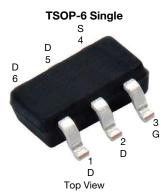
SQ3418EV

www.vishay.com

Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified ^d
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



FREE

(1, 2, 5, 6) D (3) G (4) S N-Channel MOSFET

Marking Code: 8P

| PRODUCT SUMMARY | | | | |
|--|--------|--|--|--|
| V _{DS} (V) | 40 | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$ | 0.032 | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 V$ | 0.042 | | | |
| I _D (A) | 8 | | | |
| Configuration | Single | | | |

| ORDERING INFORMATION | |
|---------------------------------|---|
| Package | TSOP-6 |
| Lead (Pb)-free and halogen-free | SQ3418EV (for detailed order number please see www.vishay.com/doc?79771) |

| ABSOLUTE MAXIMUM RATING | S (T _C = 25 °C, unles | s otherwise noted | ł) | |
|---|---|-----------------------------------|-------------|----|
| PARAMETER | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V _{DS} | 40 | V |
| Gate-Source Voltage | V _{GS} | ± 20 | v | |
| Continuous Drain Current | T _C = 25 °C ^a | I | 8 | |
| | T _C = 125 °C | I _D | 5 | |
| Continuous Source Current (Diode Conduction | on) | I _S | 6 | А |
| Pulsed Drain Current ^b | | I _{DM} | 32 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | 13.5 | |
| Single Pulse Avalanche Energy | L = 0.1 MH | E _{AS} | 9.1 | mJ |
| Maximum Power Dissipation ^b | T _C = 25 °C | PD | 5 | W |
| | T _C = 125 °C | | 1.6 | vv |
| Operating Junction and Storage Temperature | e Range | T _J , T _{stg} | -55 to +175 | °C |

| THERMAL RESISTANCE RATINGS | | | | | | | |
|----------------------------|------------------------|-------------------|-------|------|--|--|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | | | |
| Junction-to-Ambient | PCB Mount ^c | R _{thJA} | 110 | °C/W | | | |
| Junction-to-Foot (Drain) | | R _{thJF} | 30 | 0/10 | | | |

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

Parametric verification ongoing

S22-0224-Rev. B, 07-Mar-2022

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SQ3418EV

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|---|--|--|--|------|-------|-------|------|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0, I_D = 250 \ \mu A$ | | 40 | - | - | v |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | = V _{GS} , I _D = 250 μΑ | 1.5 | 2.0 | 2.5 | v |
| Gate-Source Leakage | I _{GSS} | V _{DS} = | 0 V, $V_{GS} = \pm 20$ V | - | - | ± 100 | nA |
| | | $V_{GS} = 0 V$ | V _{DS} = 40 V | - | - | 1 | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{GS} = 0 V$ | V _{DS} = 40 V, T _J = 125 °C | - | - | 50 | μA |
| | | $V_{GS} = 0 V$ | V _{DS} = 40 V, T _J = 175 °C | - | - | 150 | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 10 | - | - | Α |
| | | $V_{GS} = 10 V$ | I _D = 5 A | - | 0.026 | 0.032 | |
| Drain Source On State Desistance 3 | | $V_{GS} = 10 V$ | I _D = 5 A, T _J = 125 °C | - | - | 0.050 | Ω |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | $V_{GS} = 10 V$ | I _D = 5 A, T _J = 175 °C | - | - | 0.061 | |
| | | $V_{GS} = 4.5 V$ | I _D = 4 A | - | 0.032 | 0.042 | |
| Forward Transconductance b | g fs | V _{DS} = 15 V, I _D = 4 A | | - | 21 | - | S |
| Dynamic ^b | <u>.</u> | | | | | | |
| Input Capacitance | C _{iss} | | | - | 452 | 678 | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$ | V _{DS} = 20 V, f = 1 MHz | - | 81 | 121 | pF |
| Reverse Transfer Capacitance | C _{rss} | 1 | | - | 36 | 53 | |
| Total Gate Charge ^c | Qg | | | - | 8.5 | 12.7 | |
| Gate-Source Charge ^c | Q _{gs} | $V_{GS} = 10 V$ | $V_{DS} = 20 \text{ V}, \text{ I}_{D} = 4 \text{ A}$ | - | 1.1 | - | nC |
| Gate-Drain Charge ^c | Q _{gd} | 1 | | - | 2.0 | - | |
| Gate Resistance | Rg | f = 1 MHz | | 1.0 | 2.0 | 3.0 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | | | - | 6 | 8 | |
| Rise Time ^c | t _r | $\label{eq:VDD} \begin{array}{l} V_{DD} = 20 \ \text{V}, \ \text{R}_L = 4 \ \Omega \\ \text{I}_D \cong 5 \ \text{A}, \ \text{V}_{\text{GEN}} = 10 \ \text{V}, \ \text{R}_g = 1 \ \Omega \end{array}$ | | - | 28 | 37 | - ns |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 12 | 16 | |
| Fall Time ^c | t _f | | | - | 37 | 50 | |
| Source-Drain Diode Ratings and Chara | acteristics ^b (T _C = | = 25 °C) | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 32 | А |
| Forward Voltage | V _{SD} | le le | = 3 A, V _{GS} = 0 | _ | 0.8 | 1.2 | V |

Notes

e. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$

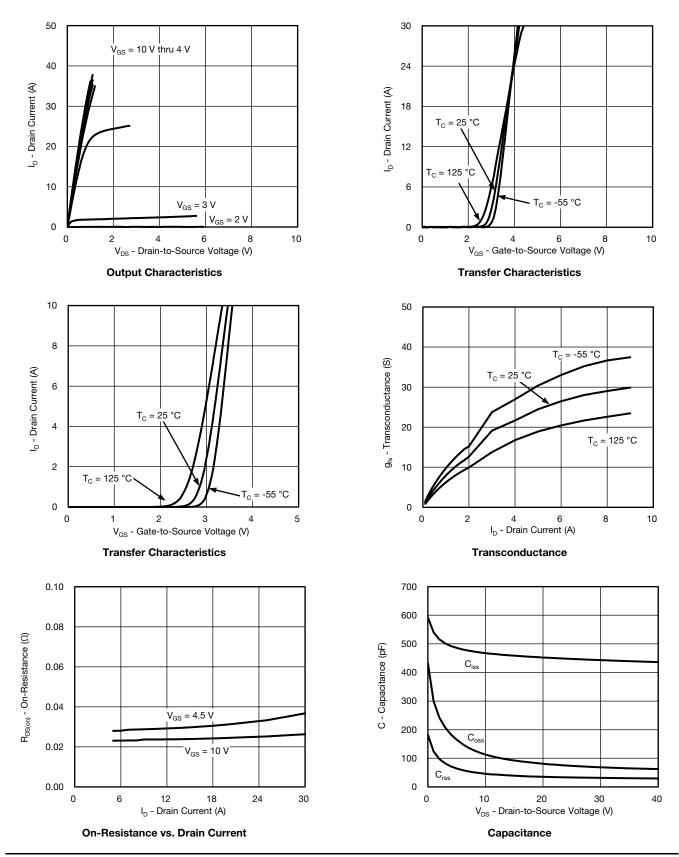
f. Guaranteed by design, not subject to production testing

g. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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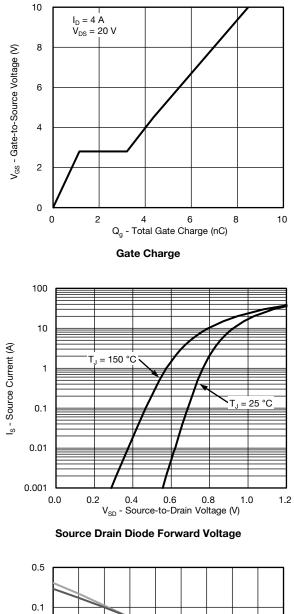
3

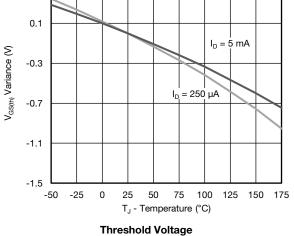
Document Number: 63412

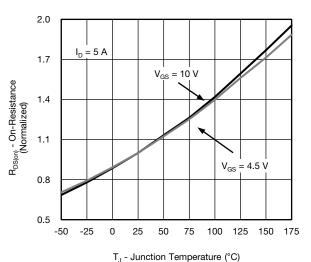
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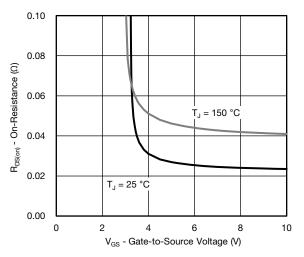
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



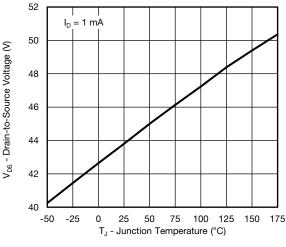




On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

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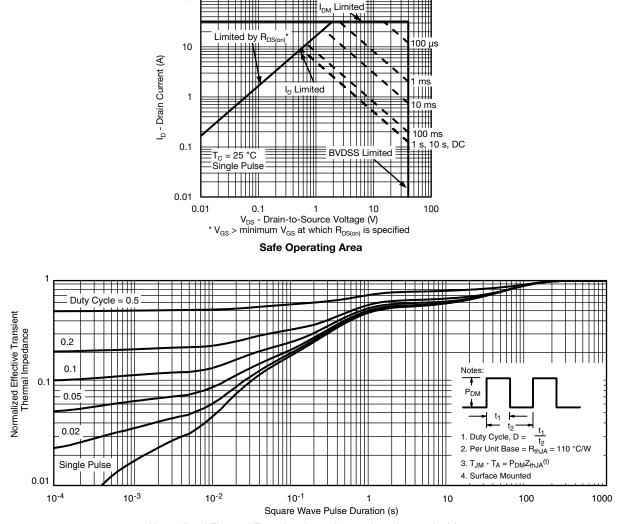
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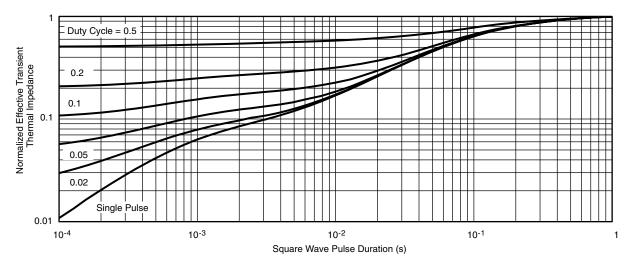
THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

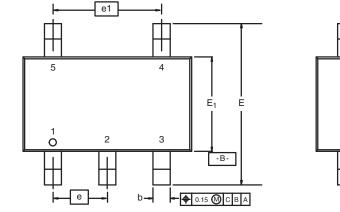
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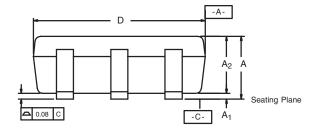
Package Information

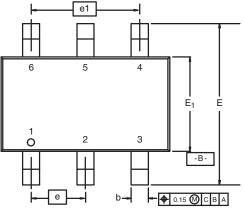
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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C

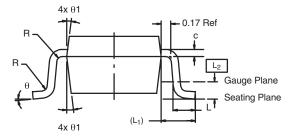


5-LEAD TSOP





6-LEAD TSOP



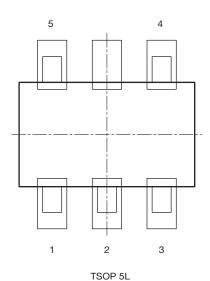
| | MILLIMETERS | | | INCHES | | |
|-----------------------|-------------|---------------|------|------------|-----------|-------|
| Dim | Min | Nom | Max | Min | Nom | Max |
| Α | 0.91 | - | 1.10 | 0.036 | - | 0.043 |
| A ₁ | 0.01 | - | 0.10 | 0.0004 | - | 0.004 |
| A ₂ | 0.90 | - | 1.00 | 0.035 | 0.038 | 0.039 |
| b | 0.30 | 0.32 | 0.45 | 0.012 | 0.013 | 0.018 |
| С | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| D | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 |
| Е | 2.70 | 2.85 | 2.98 | 0.106 | 0.112 | 0.117 |
| E ₁ | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 |
| е | | 0.95 BSC | | 0.0374 BSC | | |
| e ₁ | 1.80 | 1.90 | 2.00 | 0.071 | 0.075 | 0.079 |
| L | 0.32 | - | 0.50 | 0.012 | - | 0.020 |
| L ₁ | | 0.60 Ref | | | 0.024 Ref | |
| L ₂ | | 0.25 BSC | | 0.010 BSC | | |
| R | 0.10 | - | - | 0.004 | - | - |
| θ | 0° | 4° | 8° | 0° | 4° | 8° |
| θ_1 | 7° Nom | | | 7° Nom | | |
| ECN: C DWG: 5 | | ev. I, 18-Dec | c-06 | | | |

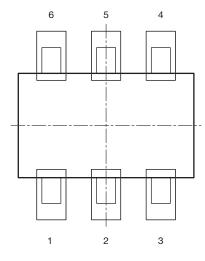
PAD Pattern



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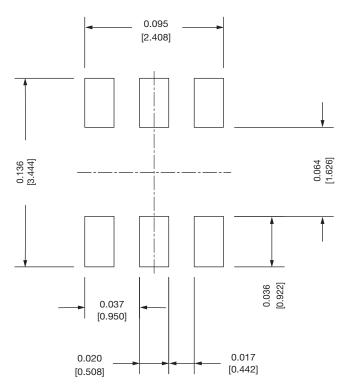
Recommended Land Pattern For TSOP-5L / TSOP-6L











Note

• All dimensions are in inches (millimeter)

| ECN: C22-0860-Rev. | B, 24-Oct-2022 | | |
|--------------------|----------------|--|--|
| DWG: 3010 | | | |



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